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**Kim**

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- (54) **ORGANIC LIGHT-EMITTING DISPLAY APPARATUS**
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1/133514; G02F 1/134309  
See application file for complete search history.

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CPC ..... **H01L 51/5237** (2013.01)

- (57) **ABSTRACT**  
An organic light-emitting display apparatus includes: a  
substrate; a display unit on the substrate and including a  
display area and a non-display area outside of the display  
area; and a thin-film encapsulation layer that seals the  
display unit, wherein the non-display area includes a dam  
region located outside of the display area and a plurality of  
protrusions on at least a part of the display unit outside of the  
dam region.

**14 Claims, 4 Drawing Sheets**

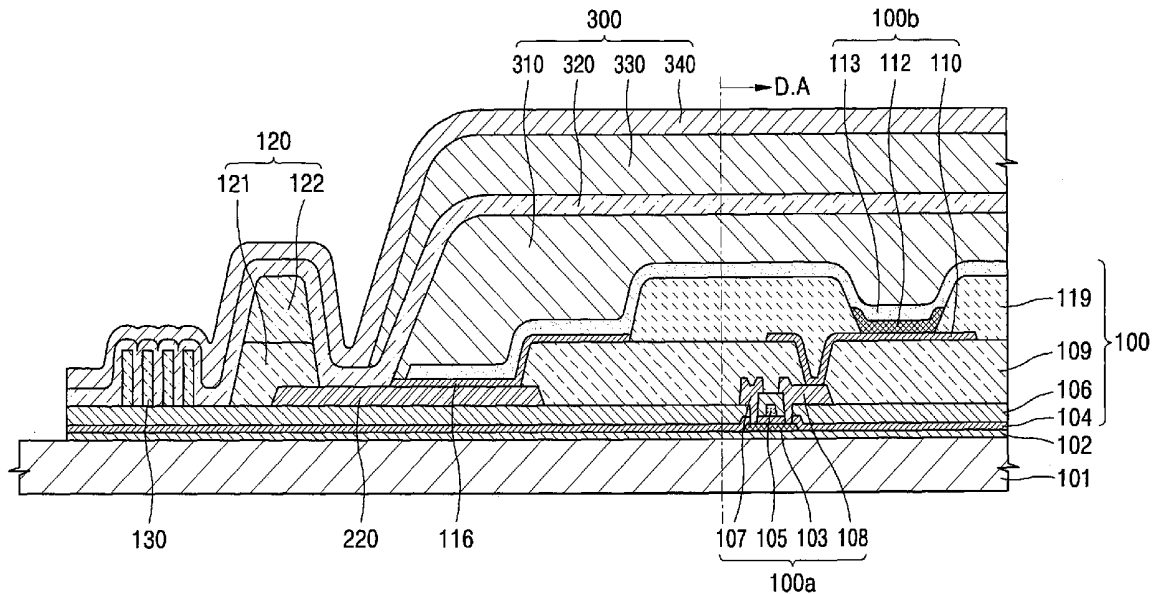


FIG. 1

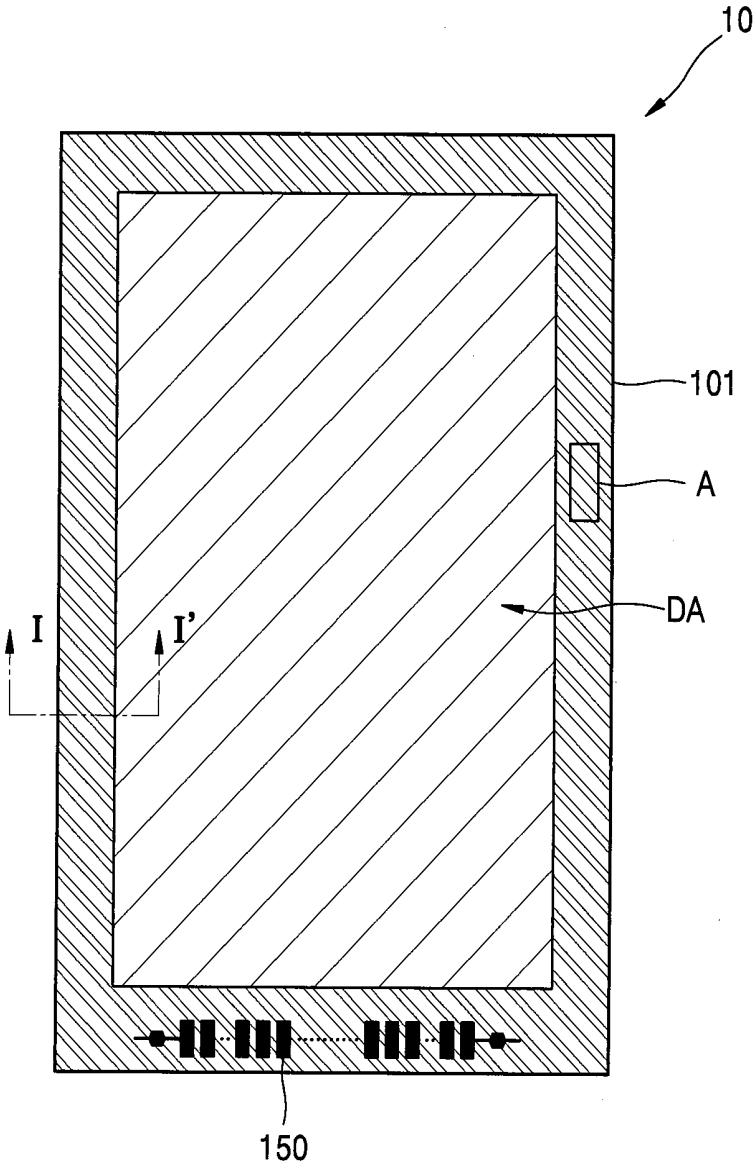


FIG. 2

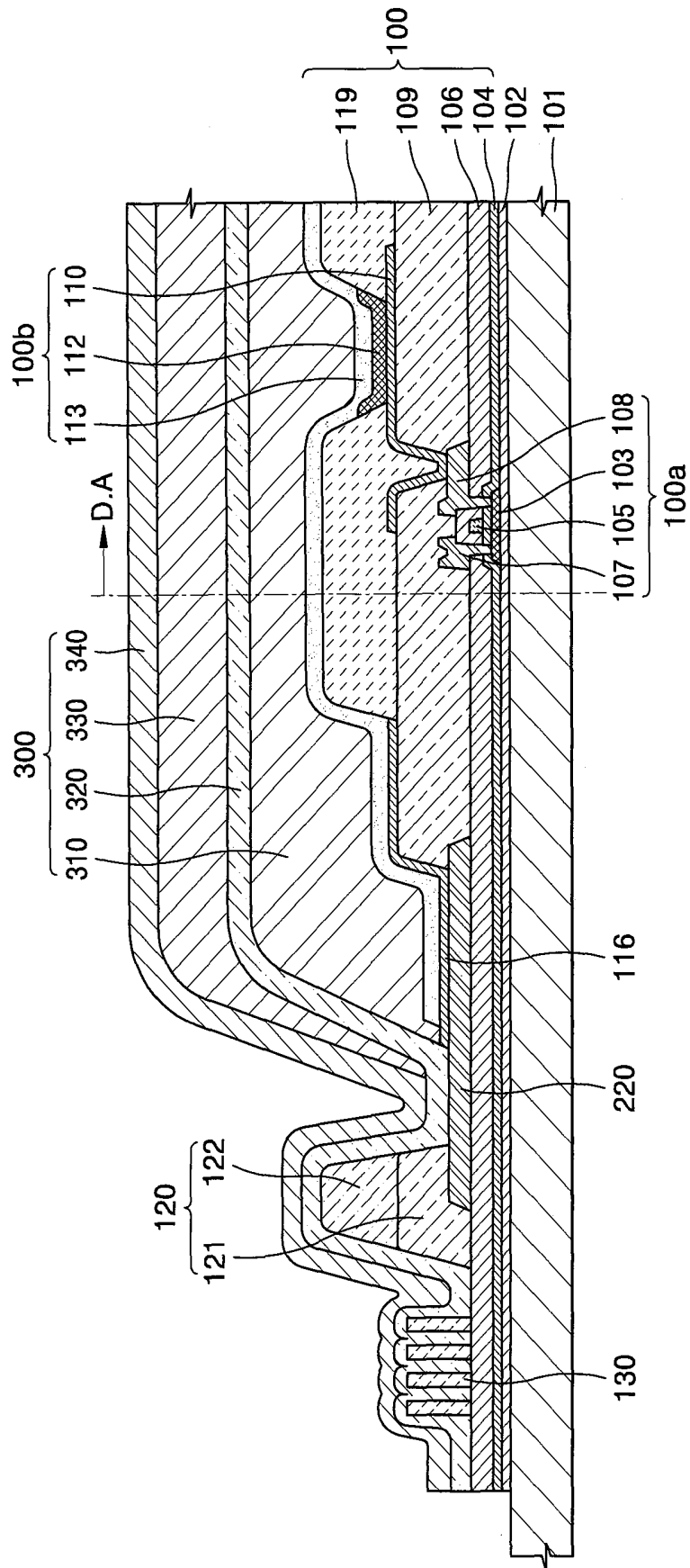


FIG. 3

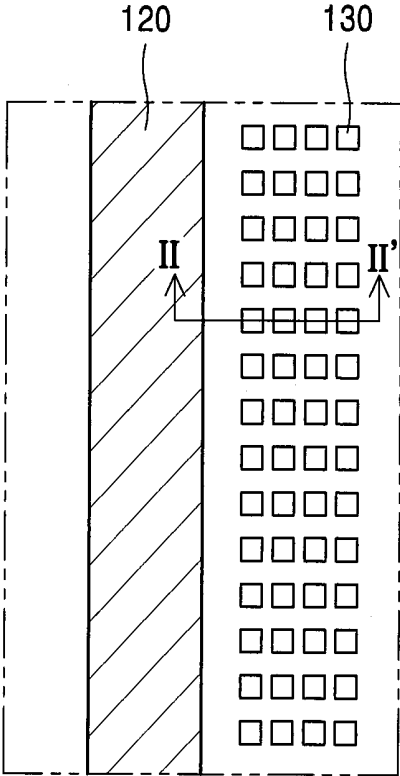


FIG. 4

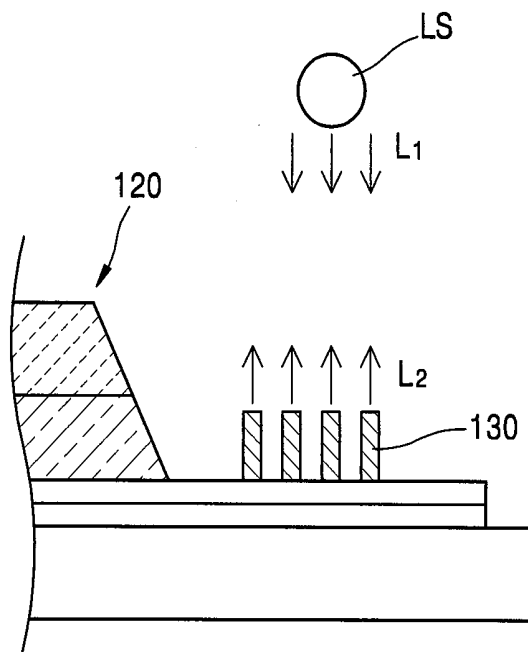
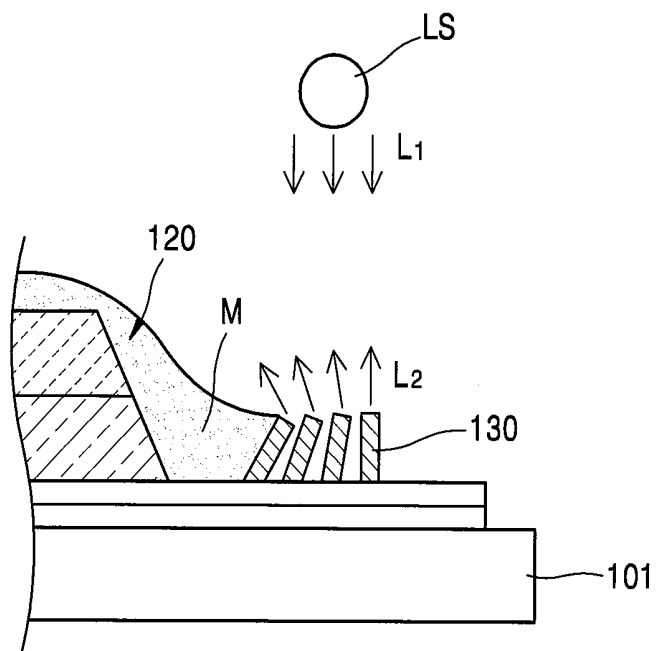


FIG. 5



## ORGANIC LIGHT-EMITTING DISPLAY APPARATUS

### CROSS-REFERENCE TO RELATED APPLICATION

This application claims priority to and the benefit of Korean Patent Application No. 10-2015-0043297, filed on Mar. 27, 2015, in the Korean Intellectual Property Office, the entire content of which is incorporated herein by reference.

### BACKGROUND

#### 1. Field

One or more example embodiments relate to an organic light-emitting display apparatus.

#### 2. Description of the Related Art

An organic light-emitting display apparatus includes an organic light-emitting device including a hole injection electrode, an electron injection electrode, and an organic emission layer disposed therebetween, and is a self-emission type (or kind of) display apparatus in which holes injected from the hole injection electrode and electrons injected from the electron injection electrode combine in the organic emission layer to generate excitons that change from an excited state to a ground state to emit light.

Since the organic light-emitting display apparatus that is a self-emission display apparatus does not use a separate light source, the organic light-emitting display apparatus may be driven at a low voltage, may be light-weight, and may be thin. Furthermore, the organic light-emitting display apparatus is receiving attention as a next generation display apparatus owing to its high quality characteristics, such as a wide viewing angle, high contrast, and a quick response speed. However, since an organic light-emitting device is deteriorated due to penetration of external moisture or oxygen into the organic light-emitting device, external moisture or oxygen need to be blocked from penetrating into the organic light-emitting device.

### SUMMARY

One or more example embodiments include an organic light-emitting display apparatus.

Additional aspects will be set forth in part in the description which follows and, in part, will be apparent from the description, or may be learned by practice of the presented embodiments.

According to one or more example embodiments, an organic light-emitting display apparatus includes: a substrate; a display unit on the substrate and including a display area and a non-display area outside of the display area; and a thin-film encapsulation layer that seals the display unit, wherein the non-display area includes a dam region located outside of the display area and a plurality of protrusions on at least a part of the display unit outside of the dam region.

The plurality of protrusions may form a uniform pattern.

The plurality of protrusions may be arranged in a plurality of rows and a plurality of columns.

The plurality of protrusions may surround the dam region.

A power supply wire may be located in the non-display area, and the dam region may overlap and contact at least an outer edge of the power supply wire.

The thin-film encapsulation layer may include at least one inorganic film and at least one organic film, wherein the at least one organic film may be located in the dam region.

The thin-film encapsulation layer may include a plurality of inorganic films and a plurality of organic films respectively located between the plurality of inorganic films, wherein the plurality of inorganic films may cover the plurality of protrusions.

The plurality of inorganic films may contact each other outside of the plurality of protrusions.

The display unit may include: a thin-film transistor; an organic light-emitting device electrically coupled to the thin-film transistor; a passivation film between the thin-film transistor and the organic light-emitting device; and a pixel defining film defining a pixel region of the organic light-emitting device, wherein the dam region and the plurality of protrusions may be formed of a same material as at least one selected from the passivation film and the pixel-defining film.

The dam region may include: a first layer formed of a same material as the passivation film; and a second layer on the first layer and formed of a same material as the pixel-defining film, and the plurality of protrusions may be formed of the same material as the pixel-defining film.

The thin-film transistor may include: an active layer; a gate electrode; a source electrode; and a drain electrode, wherein a gate insulating layer may be located between the active layer and the gate electrode, and an interlayer insulating film may be located between the gate electrode and the source and drain electrodes, and the gate insulating layer and the interlayer insulating film may extend to the non-display area.

The plurality of protrusions may be located on the interlayer insulating film.

The thin-film encapsulation layer may include at least one inorganic film, wherein the at least one inorganic film may contact the interlayer insulating film outside of the plurality of protrusions.

The at least one inorganic film may contact a top surface of the substrate through an edge portion of the interlayer insulating film.

### BRIEF DESCRIPTION OF THE DRAWINGS

These and/or other aspects will become apparent and more readily appreciated from the following description of the example embodiments, taken in conjunction with the accompanying drawings in which:

FIG. 1 is a plan view schematically illustrating an organic light-emitting display apparatus according to an example embodiment;

FIG. 2 is a cross-sectional view taken along a line I-I' of FIG. 1;

FIG. 3 is an enlarged view of a region A of FIG. 1; and

FIGS. 4 and 5 are cross-sectional views taken along a line II-II' of FIG. 3.

### DETAILED DESCRIPTION

Reference will now be made in more detail to example embodiments, examples of which are illustrated in the accompanying drawings. In this regard, the present example embodiments may have different forms and should not be construed as being limited to the descriptions set forth herein. Accordingly, the example embodiments are merely described below, by referring to the figures, to explain aspects of embodiments of the present description. Also, while describing one or more example embodiments, detailed descriptions about related well-known functions or

configurations that may diminish the clarity of the points of the one or more example embodiments are omitted.

It will be understood that although the terms “first”, “second”, etc. may be used herein to describe various components, these components should not be limited by these terms. These terms are only used to distinguish one component from another component.

Terms used herein are only used to describe one or more example embodiments, and are not intended to limit the one or more example embodiments. As used herein, the singular forms “a,” “an” and “the” are intended to include the plural forms as well, unless the context clearly indicates otherwise. Sizes of elements in the drawings may be exaggerated for convenience of explanation. In other words, since sizes and thicknesses of components in the drawings may be arbitrarily illustrated for convenience of explanation, the following embodiments are not limited thereto.

It will be understood that when a layer, region, or component is referred to as being “formed on,” “formed under,” “coupled to,” or “connected to” another layer, region, or component, it can be directly or indirectly formed on, formed under, coupled to, or connected to, respectively, the other layer, region, or component. That is, for example, intervening layers, regions, or components may be present.

As used herein, the term “and/or” includes any and all combinations of one or more of the associated listed items. Expressions such as “at least one of”, when preceding a list of elements, modify the entire list of elements and do not modify the individual elements of the list.

Hereinafter, one or more example embodiments will be described below in more detail with reference to the accompanying drawings. Those components that are the same or that are in correspondence with one another are rendered or identified using the same reference numeral regardless of the figure number, and redundant explanations thereof are not provided.

FIG. 1 is a plan view schematically illustrating an organic light-emitting display apparatus 10 according to an example embodiment, FIG. 2 is a cross-sectional view taken along a line I-I' of FIG. 1, FIG. 3 is an enlarged view of a region A of FIG. 1, and FIGS. 4 and 5 are cross-sectional views taken along a line II-II' of FIG. 3.

Referring to FIGS. 1 through 5, the organic light-emitting display apparatus 10 according to an example embodiment may include a substrate 101, a display unit 100 disposed on the substrate 101, and a thin-film encapsulation layer 300 sealing the display unit 100.

The substrate 101 may be formed of any one of various suitable materials. For example, the substrate 101 may be formed of a transparent glass material mainly including silicon oxide (e.g., SiO<sub>2</sub>). However, a material of the substrate 101 is not limited thereto, and the substrate 101 may be formed of a transparent plastic material to be more flexible. The transparent plastic material may include an insulating organic material, such as polyethersulphone (PES), polyacrylate (PAR), polyetherimide (PEI), polyethylene naphthalate (PEN), polyethyleneterephthalate (PET), polyphenylene sulfide (PPS), polyarylate, polyimide, polycarbonate (PC), cellulose triacetate (TAC), or cellulose acetate propionate (CAP).

When the organic light-emitting display apparatus 10 is a bottom-emission type (or kind) wherein an image is realized in a direction toward the substrate 101, the substrate 101 is formed of a transparent material. However, when the organic light-emitting display apparatus 10 is a top-emission type (or kind) wherein an image is realized in a direction opposite to the substrate 101 (e.g., a direction away from the substrate

101), the substrate 101 may not necessarily be formed of a transparent material. In this case, the substrate 101 may be formed of, for example, a metal.

When the substrate 101 is formed of a metal, the substrate 101 may include at least one selected from iron, chromium, manganese, nickel, titanium, molybdenum, stainless steel (SUS), invar alloy, inconel alloy, and kovar alloy, but the substrate is not limited thereto.

The display unit 100 may be formed on the substrate 101. The display unit 100 may include a display area DA for realizing an image recognizable (viewable) by a user, and a non-display area outside of the display area DA. An organic light-emitting device 100b (shown in FIG. 2) may be disposed in the display area DA, and a power supply wire 220 supplying power to the organic light-emitting device 100b may be disposed in the non-display area. Also, a pad unit 150 transmitting an electric signal from a power supply device or a signal generating device to the display area DA may be disposed in the non-display area. The display unit 100 will now be described in more detail with reference to FIG. 2.

A buffer layer 102 may be formed on the substrate 101. The buffer layer 102 may provide a flat surface on the substrate 101, and prevent or reduce an impurity or moisture from penetrating through the substrate 101.

For example, the buffer layer 102 may contain or include an inorganic material, such as silicon oxide, silicon nitride, silicon oxynitride, aluminum oxide, aluminum nitride, titanium oxide, or titanium nitride; or an organic material, such as polyimide, polyester, or acryl; or may include a plurality of layers formed of or including the above-mentioned materials. The buffer layer 102 may be formed on the display area DA, and may extend to the non-display area.

A thin-film transistor 100a and the organic light-emitting device 100b electrically coupled or connected to the thin-film transistor 100a may be located in the display area DA.

The thin-film transistor 100a may include an active layer 103, a gate electrode 105, a source electrode 107, and a drain electrode 108.

Hereinafter, it is assumed that the thin-film transistor 100a is a top gate type (or kind) wherein the active layer 103, the gate electrode 105, the source electrode 107, and the drain electrode 108 are sequentially formed in the stated order. However, the present disclosure is not limited thereto, and the thin-film transistor 100a may be any suitable type (or kind), such as a bottom gate type (or kind).

In some embodiments, the active layer 103 is formed on the buffer layer 102. The active layer 103 may include a semiconductor material, such as amorphous silicon or polycrystalline silicon. However, the present disclosure is not limited thereto, and the active layer 103 may include any one of various suitable materials. According to an example embodiment, the active layer 103 may include an organic semiconductor material.

According to another example embodiment, the active layer 103 may include an oxide semiconductor material. For example, the active layer 103 may include an oxide of a material selected from among 12-, 13-, and 14-group metal elements (e.g., group 12, 13, and 14 metal elements of the periodic table of elements), such as, for example, selected from zinc (Zn), indium (In), gallium (Ga), tin (Sn), cadmium (Cd), and germanium (Ge), and a combination thereof.

A gate insulating layer 104 is formed on the active layer 103. The gate insulating layer 104 may include a single film or a plurality of films formed of an inorganic material, such as silicon oxide and/or silicon nitride.

The gate insulating layer **104** insulates the active layer **103** and the gate electrode **105** from each other. The gate insulating layer **104** may be formed or located not only in the display area DA, but may also be formed or located in a part of the non-display area.

The gate electrode **105** is formed on the gate insulating layer **104**. The gate electrode **105** may be coupled or connected to a gate line that applies an on/off signal to the thin-film transistor **100a**.

The gate electrode **105** may be formed of a low-resistance metal material. The gate electrode **105** may include a single layer or multiple layers (a plurality of layers) formed of, for example, at least one selected from aluminum (Al), platinum (Pt), palladium (Pd), silver (Ag), magnesium (Mg), gold (Au), nickel (Ni), neodymium (Nd), iridium (Ir), chromium (Cr), lithium (Li), calcium (Ca), molybdenum (Mo), titanium (Ti), tungsten (W), and copper (Cu), considering adhesion of the gate electrode **105** to an adjacent layer, surface flatness of a stacked layer including the gate electrode **105**, and processability.

An interlayer insulating film **106** is formed on the gate electrode **105**. The interlayer insulating film **106** insulates the gate electrode **105** from the source and gate electrodes **107** and **108**. The interlayer insulating film **106** may be formed or located not only in the display area DA, but may also be formed or located in a part of the non-display area.

The interlayer insulating film **106** may include a single film or multiple of films (a plurality of films) formed of inorganic material. For example, the inorganic material may be metal oxide or metal nitride. In more detail, examples of the inorganic material include silicon oxide (SiO<sub>2</sub>), silicon nitride (SiN<sub>x</sub>; 1/2 ≤ x ≤ 4/3), silicon oxynitride (SiON), aluminum oxide (Al<sub>2</sub>O<sub>3</sub>), titanium oxide (TiO<sub>2</sub>), tantalum oxide (Ta<sub>2</sub>O<sub>5</sub>), hafnium oxide (HfO<sub>2</sub>), and zinc oxide (ZnO).

The source and drain electrodes **107** and **108** are formed on the interlayer insulating film **106**. The source and drain electrodes **107** and **108** may each include a single layer or a multilayer (a plurality of layers) formed of at least one material selected from among Al, Pt, Pd, Ag, Mg, Au, Ni, Nd, Ir, Cr, Li, Ca, Mo, Ti, W, and Cu. The source and drain electrodes **107** and **108** are formed to contact (directly contact) a region of the active layer **103**.

A passivation film **109** may be formed to cover the thin-film transistor **100a**. The passivation film **109** removes a stepped portion formed by the thin-film transistor **100a** and flattens a top surface of the thin-film transistor **100a** (a top surface above the thin-film transistor **100a**), thereby preventing or reducing a defect in the organic light-emitting device **100b** caused by a lower unevenness (e.g., an unevenness due to the thin-film transistor **100a**).

The passivation film **109** may include a single film or a plurality of films formed of an organic material. Examples of the organic material include polymethyl methacrylate (PMMA), general-purpose polymer such as polystyrene (PS), polymer derivatives having a phenol-based group, acryl-based polymer, imide-based polymer, aryl ether-based polymer, amide-based polymer, fluorine-based polymer, p-xylene-based polymer, vinyl alcohol-based polymer, and a blend thereof (e.g., a blend of any of the foregoing polymers). In some embodiments, the passivation film **109** may be a complex stacked structure of an inorganic insulating film and an organic insulating film.

The organic light-emitting device **100b** is formed on the passivation film **109**.

The organic light-emitting device **100b** is electrically coupled or connected to the thin-film transistor **100a**, and

includes a first electrode **110**, a second electrode **113** facing the first electrode **110**, and an intermediate layer **112** disposed between the first electrode **110** and the second electrode **113**.

The first electrode **110** may be electrically coupled or connected to the gate electrode **108**. The first electrode **110** may have any one of various suitable shapes. For example, the first electrode **110** may be patterned in island shapes (e.g., the first electrode may include a plurality of distinct islands that do not directly contact one another).

The first electrode **110** is formed on the passivation film **109**, and may be electrically coupled or connected to the thin-film transistor **100a** through a contact hole formed on the passivation film **109** (e.g., a contact hole passing through the passivation film **109**). The first electrode **110** may be, for example, a reflective electrode. For example, the first electrode **110** may include a reflective film formed of Ag, Mg, Al, Pt, Pd, Au, Ni, Nd, Ir, Cr, or a compound thereof, and a transparent or semi-transparent electrode layer formed on the reflective film. The transparent or semi-transparent electrode layer may be formed of a material selected from indium tin oxide (ITO), indium zinc oxide (IZO), zinc oxide (ZnO), indium oxide (In<sub>2</sub>O<sub>3</sub>), indium gallium oxide (IGO), and aluminum zinc oxide (AZO).

The second electrode **113** facing the first electrode **110** may be a transparent or semi-transparent electrode, and may include a thin film formed of a metal having a low work function, such as Li, Ca, LiF/Ca, LiF/Al, Al, Ag, Mg, or a compound or a combination thereof. Also, an auxiliary electrode layer or a bus electrode may be further formed on the thin film by using a transparent electrode forming material, such as ITO, IZO, ZnO, or In<sub>2</sub>O<sub>3</sub>. Accordingly, the second electrode **113** may transmit light emitted from an organic emission layer included in the intermediate layer **112**. For example, light emitted from the organic emission layer may be transmitted to the second electrode **113** directly or after being reflected at the first electrode **110**, which may be a reflective electrode.

However, a type (or kind) of the display unit **100** according to example embodiments is not limited to a top emission type (or kind), and may be a bottom emission type (or kind) wherein light emitted from the organic emission layer is emitted towards the substrate **101**. In this case, the first electrode **110** may be a transparent or semi-transparent electrode, and the second electrode **113** may be a reflective electrode. In some embodiments, the display unit **100** according to an example embodiment may be a dual emission type (or kind) wherein light is emitted in both top and bottom directions.

Meanwhile, a pixel-defining film **119** is formed on the first electrode **110** by using an insulating material. The pixel-defining film **119** may be formed of at least one organic insulating material selected from polyimide, polyamide, acryl resin, benzocyclobutene, and phenol resin, via a spin coating method. The pixel-defining film **119** exposes a certain region of the first electrode **110**. The intermediate layer **112** including the organic emission layer is disposed in the certain region (e.g., in the exposed portion). In other words, the pixel-defining film **119** defines a pixel region of the organic light-emitting device **100b**.

The organic emission layer included in the intermediate layer **112** may be formed of a low molecular organic material or a high molecular organic material (e.g., a low molecular weight organic material or a high molecular weight organic material), and the intermediate layer **112** may further include a functional layer, such as a hole transport layer (HTL), a hole injection layer (HIL), an electron

transport layer (ETL), or an electron injection layer (EIL), as well as the organic emission layer.

A dam region **120** and a plurality of protrusions **130** may be located in the non-display area outside of the display area DA. In addition, the non-display area may include various suitable circuit patterns, such as the power supply wire **220** and a static electricity preventing pattern (e.g., a pattern that prevents or reduces generation of static electricity).

The power supply wire **220** includes a common voltage line ELVSS and a driving voltage line ELVDD, and may be formed of a same (substantially the same) material as the source and drain electrodes **107** and **108**. In FIG. 2, the common voltage line ELVSS of the power supply wire **220** is illustrated, and the common voltage line ELVSS and the second electrode **113** are coupled or connected to each other through a wire **116**, but the present disclosure is not limited thereto. For example, the common voltage line ELVSS and the second electrode **113** may be directly coupled or connected to each other.

The dam region **120** is disposed outside of the display area DA to prevent or reduce organic materials for forming organic films **310** and **330** of the thin-film encapsulation layer **300** from flowing towards an edge of the substrate **101** while forming the organic films **310** and **330**, thereby preventing or reducing an edge tail of the organic films **310** and **330** from being formed. The dam region **120** may be formed to surround (partially or completely surround) the display area DA.

The dam region **120** may be formed of a same (substantially the same) material as at least one selected from the passivation film **109** and the pixel-defining film **119**. For example, the dam region **120** may include a first layer **121** formed of the same (substantially the same) material as the passivation film **109**, and a second layer **122** formed on the first layer **121** and formed of the same (substantially the same) material as the pixel-defining film **119**. However, the present disclosure is not limited thereto, and the dam region **120** may include one layer (e.g., the dam region **120** may include a sole layer). Also, there may be a plurality of the dam regions **120**. In this case, heights of the dam regions **120** may increase towards the outside of the substrate **101** (e.g., a height of a dam closer to an edge of the substrate **101** may be larger than a height of a dam further from the edge of the substrate **101**).

The dam region **120** may overlap and contact (directly contact) at least a part of the power supply wire **220**. For example, the dam region **120** may overlap and contact (directly contact) at least an outer edge of the power supply wire **220**. The dam region **120** formed of the same (substantially the same) material as at least one selected from the passivation film **109** and the pixel-defining film **119** may have excellent bonding power (adhesion) to a metal. Accordingly, when the dam region **120** contacts the power supply wire **220** formed of a metal material, the dam region **120** may be stably formed with excellent bonding power (adhesion).

For example, in FIG. 2, the dam region **120** overlaps the outer edge of the power supply wire **220**, but the present disclosure is not limited thereto. In some embodiments, the dam region **120** may be formed only on the power supply wire **220** or to cover the power supply wire **220**.

The plurality of protrusions **130** may be formed on at least a part outside of the dam region **120**. The protrusions **130** are located on the interlayer insulating film **106**, and may be formed of the same (substantially the same) material as at least one selected from the passivation film **109** and the pixel-defining film **119**.

The protrusions **130** may have a height lower than that of the dam region **120**. For example, when the dam region **120** includes the first layer **121** formed of the same (substantially the same) material as the passivation film **109** and the second layer **122** formed on the first layer **121** and formed of the same (substantially the same) material as the pixel-defining film **119**, the protrusions **130** may be formed of the same (substantially the same) material as the pixel-defining film **119**.

The protrusions **130** may have a uniform (substantially uniform) pattern outside of the dam region **120**. The protrusions **130** may be spaced apart from each other at regular (substantially regular) intervals. For example, the protrusions **130** may be disposed in a plurality of rows and a plurality of columns. The number of rows and columns of the protrusions **130** are not limited. However, as will be described below, the number of columns of the protrusions **130** may be at least three so as to recognize a pattern change of reflection light **L2** reflected by the protrusions **130** (e.g., so that a change in a pattern of light **L2** reflected by the protrusions **130** may be detected). The protrusions **130** may have any one of various suitable shapes, such as a pillar shape and/or a horn shape.

The protrusions **130** are used to easily recognize the organic material for forming the organic films **310** and **330** flowing outside of the substrate **101** over the dam region **120** (e.g., flow of the organic material for forming the organic films **310** and **330** over the dam region **120** may be detected by way of the protrusions **130**). When the organic material for forming the organic films **310** and **330** flows outside of the substrate **101** over the dam region **120**, edge tails of the organic films **310** and **330** may be formed. In this case, external moisture or oxygen may penetrate into the organic light-emitting display apparatus **10** through the edge tails, thereby causing a defect, such as a dark spot, in the organic light-emitting display apparatus **10**.

FIGS. 4 and 5 are cross-sectional views taken along a line II-II' of FIG. 3, wherein in FIG. 4, an organic material M for forming the organic films **310** and **330** only exists on an inner region of the dam region **120** and in FIG. 5, the organic material M flows outside of the substrate **101** over the dam region **120**.

As shown in FIG. 4, when flow of the organic material M is blocked by the dam region **120**, shapes of the protrusions **130** outside of the dam region **120** remain intact (e.g., the position and/or shape of each of the protrusions **130** has not been changed or altered by the flow of the organic material). Accordingly, when light **L1** is irradiated on or to the protrusions **130** from an external light source **LS**, the reflection light **L2** reflected at the protrusions **130** having a uniform (substantially uniform) pattern may also have a uniform (substantially uniform) pattern.

However, as shown in FIG. 5, when the organic material M flows outside of the substrate **101** over the dam region **120**, the shapes (and/or positions) of the protrusions **130** may be changed by the organic material M. For example, some of the protrusions **130** may be tilted or may fall in a direction towards the outside of the substrate **101** by the organic material M. When the shapes of the protrusions **130** are changed as such and the light **L1** is irradiated from the light source **LS**, a reflection pattern of the reflection light **L2** is changed by the protrusions **130**. Thus, overflow of the organic material M may be easily identified (detected).

The protrusions **130** may be formed throughout and around the dam region **120**. When the protrusions **130** are disposed to surround (partially or completely surround) the dam region **120**, the overflow of the organic material M may

be easily and quickly detected throughout and around the dam regions 120. In other words, since a defect may be easily determined while manufacturing the organic light-emitting display apparatus 10, a yield of the organic light-emitting display apparatus 10 may be increased.

Also, in some embodiments, the protrusions 130 have a concave-convex structure, and a first inorganic film 320 and a second inorganic film 340 of the thin-film encapsulation layer 300 may be formed to cover the protrusions 130 as will be described below. Accordingly, a penetration length of external moisture and oxygen may be increased.

The thin-film encapsulation layer 300 may seal the display unit 100 to prevent or reduce external oxygen and moisture from penetrating into the display unit 100. The thin-film encapsulation layer 300 may include the organic films 310 and 330 and the first and second inorganic films 320 and 340.

The organic films 310 and 330 and the first and second inorganic films 320 and 340 may be alternately stacked on each other to form a multilayer structure. In FIG. 2, the thin-film encapsulation layer 300 includes two organic films 310 and 330 and two first and second inorganic films 320 and 340, but the present disclosure is not limited thereto. For example, the thin-film encapsulation layer 300 may further include a plurality of inorganic encapsulation films and a plurality of organic encapsulation films, which are alternately disposed, wherein a number of times the inorganic encapsulation films and the organic encapsulation films are stacked on each other is not limited.

The organic films 310 and 330 may include at least one material selected from acryl-based resin, methacryl-based resin, polyisoprene, vinyl-based resin, epoxy-based resin, urethane-based resin, cellulose-based resin, and perylene-based resin.

Meanwhile, since the dam region 120 prevents or reduces the organic material M from flowing towards the edge of the substrate 101 while forming the organic films 310 and 330, the organic films 310 and 330 are located in (inside) the dam region 120.

The first and second inorganic films 320 and 340 may include at least one material selected from silicon nitride, aluminum nitride, zirconium nitride, titanium nitride, hafnium nitride, tantalum nitride, silicon oxide, aluminum oxide, titanium oxide, tin oxide, cerium oxide, and silicon oxynitride.

The first and second inorganic films 320 and 340 are formed to be larger than the organic films 310 and 330 and to cover the dam region 120 and the protrusions 130 that are concave and convex. Accordingly, a penetration length of external moisture and oxygen may be increased, thereby delaying, blocking, or reducing penetration of the external moisture and oxygen.

The first and second inorganic films 320 and 340 may extend outside of the protrusions 130, and may contact (directly contact) each other outside of the protrusions 130 (e.g., at least one of the first and second inorganic films 320 and 340 may directly contact at least one other of the first and second inorganic films 320 and 340 in a region outside of the protrusions 130). Also, at least one selected from the first and second inorganic films 320 and 340 may contact (directly contact) the interlayer insulating film 106 outside of the protrusions 130. Accordingly, bonding power (adhesion) of the thin-film encapsulation layer 300 may be increased and external moisture may be prevented or reduced from being permeated.

Also, at least one selected from the first and second inorganic films 320 and 340 may contact (directly contact)

a top surface of the substrate 10 through an edge portion of the interlayer insulating film 106 outside of the protrusions 130, and may also contact (directly contact) side surfaces of the gate insulating layer 104 and interlayer insulating film 106. Accordingly, an encapsulation characteristic of the thin-film encapsulation layer 300 may be prevented or reduced from being weakened or removed due to detachment of edges of the first and second inorganic films 320 and 340.

According to an organic light-emitting display apparatus according to an example embodiment, penetration of external moisture or oxygen may be blocked or reduced by preventing or reducing an edge tail of an organic film of a thin-film encapsulation layer from being formed, and overflow of an organic material for forming an organic film may be easily determined.

While one or more example embodiments have been described with reference to the figures, it will be understood by those of ordinary skill in the art that various changes in form and details may be made therein without departing from the spirit and scope as defined by the following claims, and equivalents thereof.

What is claimed is:

1. An organic light-emitting display apparatus comprising:

a substrate;

a display unit on the substrate and comprising a display area and a non-display area outside of the display area; and

a thin-film encapsulation layer that seals the display unit, wherein the non-display area comprises a dam region located outside of the display area and a plurality of protrusions on at least a part of the display unit outside of the dam region.

2. The organic light-emitting display apparatus of claim 1, wherein the plurality of protrusions form a uniform pattern.

3. The organic light-emitting display apparatus of claim 1, wherein the plurality of protrusions are arranged in a plurality of rows and a plurality of columns.

4. The organic light-emitting display apparatus of claim 1, wherein the plurality of protrusions surround the dam region.

5. The organic light-emitting display apparatus of claim 1, wherein a power supply wire is located in the non-display area, and the dam region overlaps and contacts at least an outer edge of the power supply wire.

6. The organic light-emitting display apparatus of claim 1, wherein the thin-film encapsulation layer comprises at least one inorganic film and at least one organic film, wherein the at least one organic film is located in the dam region.

7. The organic light-emitting display apparatus of claim 1, wherein the thin-film encapsulation layer comprises a plurality of inorganic films and a plurality of organic films respectively located between the plurality of inorganic films, wherein the plurality of inorganic films cover the plurality of protrusions.

8. The organic light-emitting display apparatus of claim 7, wherein the plurality of inorganic films contact each other outside of the plurality of protrusions.

9. The organic light-emitting display apparatus of claim 1, wherein the display unit comprises: a thin-film transistor; an organic light-emitting device electrically coupled to the thin-film transistor; a passivation film between the thin-film transistor and the organic light-emitting device; and a pixel-defining film defining a pixel region of the organic light-emitting device,

wherein the dam region and the plurality of protrusions are formed of a same material as at least one selected from the passivation film and the pixel-defining film.

10. The organic light-emitting display apparatus of claim 9, wherein the dam region comprises: a first layer formed of a same material as the passivation film; and a second layer on the first layer and formed of a same material as the pixel-defining film, and

the plurality of protrusions are formed of the same material as the pixel-defining film. 10

11. The organic light-emitting display apparatus of claim 9, wherein the thin-film transistor comprises: an active layer; a gate electrode; a source electrode; and a drain electrode, wherein a gate insulating layer is located between the active layer and the gate electrode, and an interlayer insulating film is located between the gate electrode and the source and drain electrodes, and the gate insulating layer and the interlayer insulating film extend to the non-display area. 15

12. The organic light-emitting display apparatus of claim 11, wherein the plurality of protrusions are located on the interlayer insulating film. 20

13. The organic light-emitting display apparatus of claim 11, wherein the thin-film encapsulation layer comprises at least one inorganic film, wherein the at least one inorganic film contacts the interlayer insulating film outside of the plurality of protrusions. 25

14. The organic light-emitting display apparatus of claim 13, wherein the at least one inorganic film contacts a top surface of the substrate through an edge portion of the interlayer insulating film. 30

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专利名称(译)	有机发光显示装置		
公开(公告)号	<a href="#">US9685626</a>	公开(公告)日	2017-06-20
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[标]申请(专利权)人(译)	三星显示有限公司		
申请(专利权)人(译)	三星DISPLAY CO. , LTD.		
当前申请(专利权)人(译)	三星DISPLAY CO. , LTD.		
[标]发明人	KIM MOONGON		
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摘要(译)

一种有机发光显示装置，包括：基板；基板上的显示单元，包括显示区域和显示区域外的非显示区域；以及密封显示单元的薄膜封装层，其中非显示区域包括位于显示区域外部的挡板区域和位于挡板区域外部的显示单元的至少一部分上的多个突起。

